

Dual-Rail Ultra-Low Dropout 1.5A LDO

General Description

The ET5A4ADJZB is CMOS-based low-dropout, low-power linear regulators, offering 1500mA with NMOS pass transistor and a separate bias supply voltage(V_{BIAS}). The device provides very stable, accurate output voltage with low noise, high ripple rejection and low supply current suitable for space constrained, noise sensitive application. ET5A4ADJZB consists of an accurate voltage-reference block, an error amplifier, a thermal-shutdown circuit, and a current limit circuit.

Features

- Wide V_{IN} Voltage Range: $V_{OUT}+0.15V$ to V_{BIAS}
- Wide V_{BIAS} Voltage Range: 3.0V to 5.5V
- Output Voltage Range: 0.5V to 3.0V
- Very Low V_{BIAS} Input Current: 60 μ A
- Ultra Low Dropout: 80mV at 1.5A@ $V_{OUT}=1V$
- Built-in Over-current Protection and Thermal Shutdown Circuit
- Built-in Auto-discharging Circuit (optional)
- Built-in Under Voltage Lock-out
- Package Information:

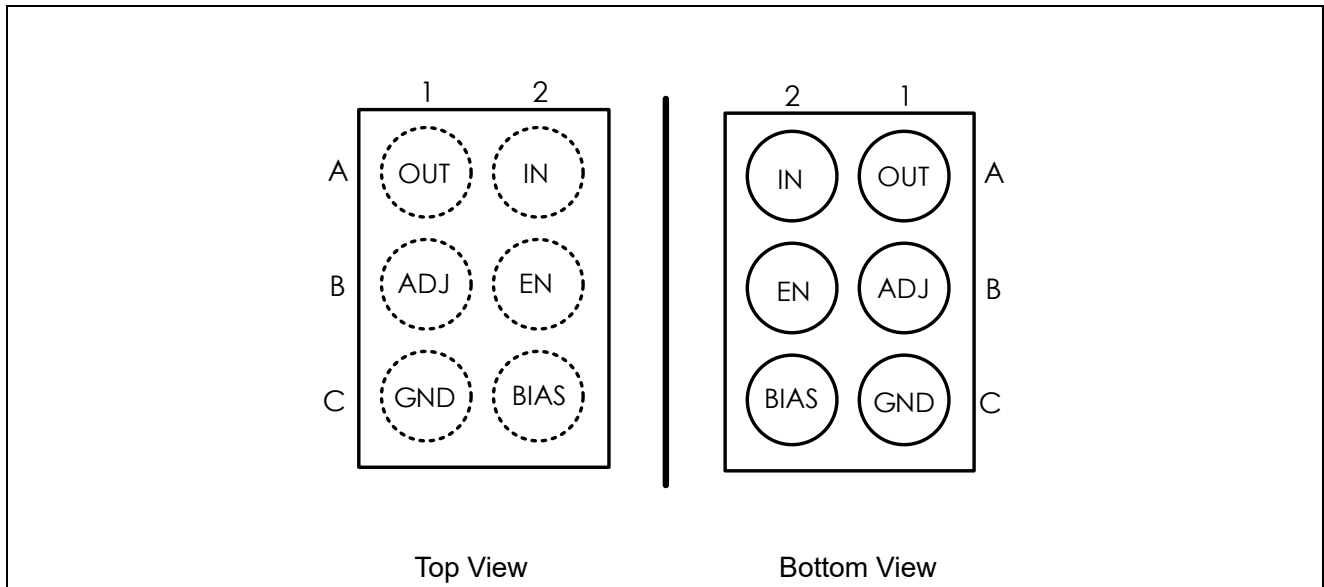
Part No.	Package	MSL
ET5A4ADJZB	WLCSP6 (1.2mm×0.8mm×0.35mm,0.4pitch)	Level 1

Applications

- Telecom Industrial and Consumer Equipment
- FPGA, DSP and Logic Power Supplies
- Switching Power Supply Post Regulation
- Specific Start-up Time or Sequencing Requirement Applications

ET5A4ADJZB

Pin Configuration

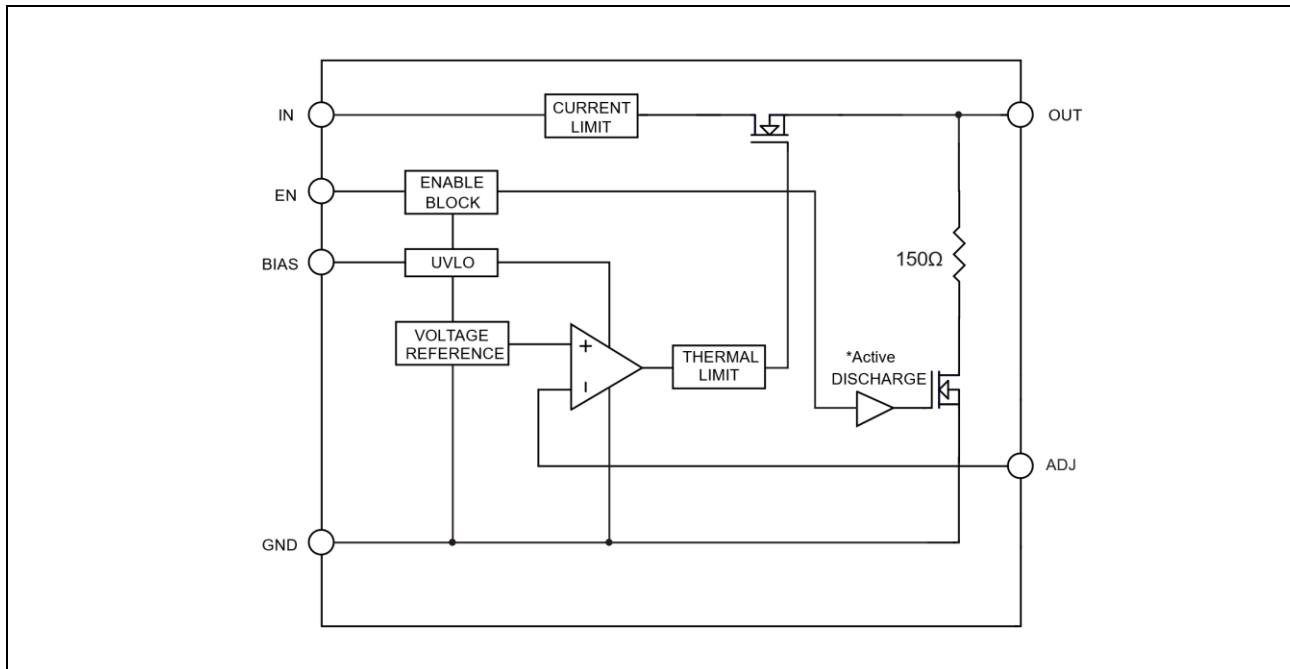


Pin Function

Pin Name	Symbol	Pin Description
A1	OUT	The power output of the device. A 22 μ F (typ.) ceramic capacitor is recommended at this pin.
A2	IN	Input voltage Pin. Large bulk capacitance should be placed closely to this pin. A 10 μ F (typ.) ceramic capacitor is recommended at this pin.
B1	ADJ	Adjustable Regulator Feedback Input. Connect to output voltage resistor divider central node.
B2	EN	Enable Input.
C1	GND	Ground pin.
C2	BIAS	Input voltage for controlling circuit.

ET5A4ADJZB

Block Diagram



Functional Description

The ET5A4ADJZB dual-rail very low dropout voltage regulator is using NMOS pass transistor for output voltage regulation from V_{IN} voltage. All the low current internal control circuitry is powered from the V_{BIAS} voltage.

The use of an NMOS pass transistor offers several advantages in applications. Unlike PMOS topology devices, the output capacitor has reduced impact on loop stability. V_{IN} to V_{OUT} operating voltage difference can be very low compared with standard PMOS regulators in very low V_{IN} applications.

The ET5A4ADJZB offers smooth start-up.

Input and Output Capacitor

The device is designed to be stable for ceramic output capacitors with 22 μ F capacitance. The device is also stable with multiple capacitors in parallel. In applications where no low input supplies impedance available (PCB inductance in V_{IN} and/or V_{BIAS} inputs as example), the recommended $C_{IN} = 10\mu$ F and $C_{BIAS} = 1\mu$ F or greater.

Enable Pin Operation

The ET5A4ADJZB is turned on by setting the EN pin to “H”. The threshold limits are covered in the electrical characteristics table in this datasheet. When the EN pin is not used, connect the EN pin with V_{BIAS} to keep the LDO in operating mode.

Current Limit Protection

When output current of V_{OUT} pin is higher than current limit threshold or the V_{OUT} pin is direct short to GND, the current limit protection will be triggered and clamp the output current at a predesigned level to prevent over-current and thermal damage.

ET5A4ADJZB

Thermal Shutdown Protection

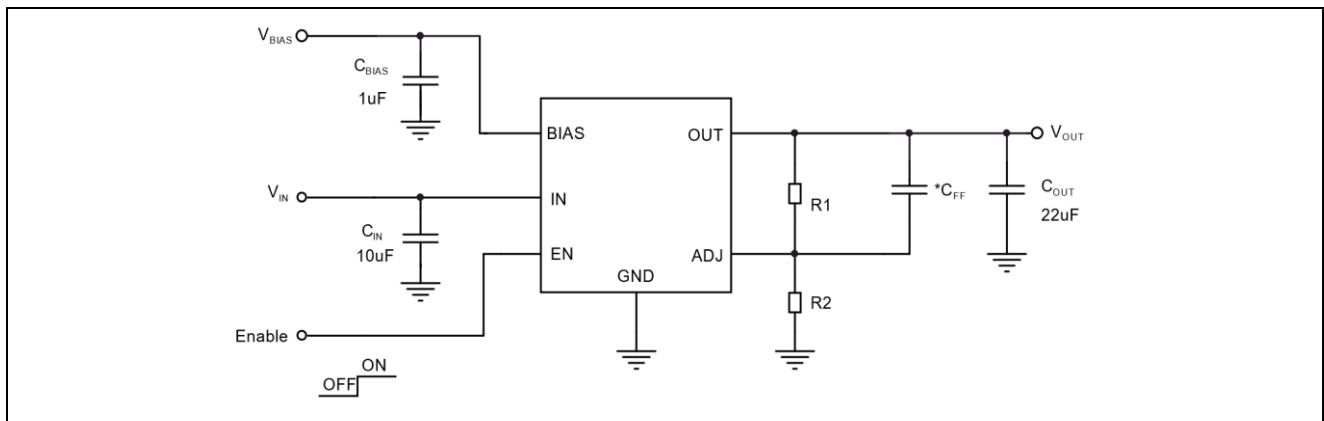
Thermal protection disables the output when the junction temperature rises to approximately +160°C, allowing the device to cool down. When the junction temperature reduces to approximately +140°C the output circuit is enabled again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator, protecting it from damage due to overheating.

Auto Discharging

When the EN pin set to “L”, the output circuit will be disabled immediately, and the Auto-Discharging circuit will be turned on to discharge the electric charge on output capacitor, and decrease the voltage of V_{OUT} in very short time.

Output Voltage Adjust

The required output voltage of Adjustable devices can be adjusted from V_{REF} to 3.0 V using two external resistors. Typical application schematics is shown below.



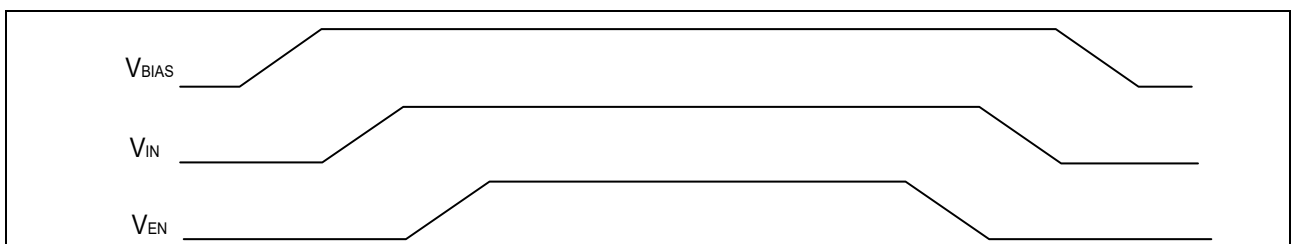
$$V_{OUT} = V_{REF} \times (1 + R1/R2)$$

Typical value of V_{REF} (ADJ Pin) is 0.5. It is recommended to keep the total serial resistance of resistors ($R1 + R2$) no greater than 100k Ω .

The output voltage needs to take into account the error caused by the resistance accuracy.

Power Up/Down Sequence Control

The recommended power on sequence of ET5A4ADJZB is to power on V_{SYS} first, then power on input power V_{IN} , then set V_{EN} to high level, and then enable LDO. The corresponding power off sequence is to turn off LDO. First, set V_{EN} to low level, then power off input power V_{IN} , and finally power off V_{SYS} .



ET5A4ADJZB

Absolute Maximum Ratings

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage(IN Pin)	-0.3 to 6.0	V
V_{BIAS}	Input Voltage (BIAS Pin)	-0.3 to 6.0	V
V_{EN}	Input Voltage (EN Pin)	-0.3 to 6.0	V
V_{FB}	Input Voltage (FB Pin)	-0.3 to 6.0	V
V_{OUT}	Output Voltage(OUT Pin)	-0.3 to 6.0	V
I_{OUT_MAX}	Maximum Load Current	1500	mA
P_{D_MAX}	Maximum Power Consumption (PCB: 5cm × 5cm, 2layer, 1oz)	1500	mW
T_{J_MAX}	Maximum Junction Temperature	-40 to 150	°C
T_{STG}	Storage Temperature Range	-65 to +150	°C
T_L	Lead Temperature (Soldering, 10 sec)	260	°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Air	66.6	°C/W
V_{ESD}	HBM (EIA/JESD22-A114-A)	±2000	V
	CDM (EIA/JESD22-C101-A)	±1500	V

Recommended Operating Conditions

Symbol	Item	Rating	Unit
V_{IN}	IN Input Voltage	$V_{OUT}+0.15$ to 5.5 & $V_{IN}<V_{BIAS}$	V
V_{BIAS}	BIAS Input Voltage	3 to 5.5 & $V_{BIAS}>V_{OUT}+1.6V$	V
I_{OUT}	Output Current	0 to 1500	mA
T_A	Operating Ambient Temperature	-40 to 85	°C
T_J	Operating Junction Temperature	-40 to 125	°C
C_{IN}	Effective Input Ceramic Capacitor Value	4.7 to 22	μF
C_{BIAS}	Effective Input Ceramic Capacitor Value	0.22 to 4.7	μF
C_{OUT}	Effective Output Ceramic Capacitor Value	6.8 to 33	μF
ESR	Input and Output Capacitor Equivalent Series Resistance	5 to 100	mΩ

ET5A4ADJZB

Electrical Characteristics

(Unless otherwise noted, $V_{IN}=V_{OUT}+0.3V$, $V_{BIAS}=3.0V$, $I_{OUT}=1mA$, $C_{IN}=10\mu F$, $C_{OUT}=22\mu F$, $C_{BIAS}=1\mu F$, $T_A=-40\sim+85^{\circ}C$. Typical values are at $T_A=25^{\circ}C$)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$V_{IN}^{(1)}$	Input Voltage Range	$V_{IN}\geq V_{OUT}+0.15V$, $T_A=25^{\circ}C$	$V_{OUT}+0.15V$		$5.5\leq V_{BIAS}$	V
V_{BIAS}	V_{BIAS} Voltage Range	$V_{BIAS}>3.0$ & $V_{BIAS}> V_{OUT}+1.6$	3.0		5.5	V
V_{UVLO}	Under-voltage lock-out	V_{BIAS} Rising	1.50	1.80	2.10	V
V_{UVLO_HYS}		Hysteresis	0.10	0.26	0.45	V
I_{Q_ON}	V_{BIAS} Current	Active mode: $V_{EN}=V_{BIAS}$	40	60	100	μA
I_{Q_OFF}		$V_{EN}=0V$		1.0	3	μA
V_{FB}	FB Voltage	$T_A=25^{\circ}C$	0.495		0.505	V
V_{OUT}	Output Voltage		0.5		3.0	V
$V_{DROP}^{(2)}$	Dropout Voltage	$I_{OUT}=1500mA$, $V_{OUT}=1.0V$		80	160	mV
I_{LIM}	Current Limit	$V_{IN}=V_{OUT}+0.2V$, $T_A=25^{\circ}C$		4		A
I_{SHORT}	Short Current Limit	$V_{OUT}=0V$		1500		mA
Reg_{LOAD}	Load Regulation	$1mA\leq I_{OUT}\leq 1500mA$ $V_{OUT}=1.0V$		4	30	mV
Reg_{LINE}	V_{IN} Line Regulation	$V_{OUT}+0.3V\leq V_{IN}\leq 5V$ $V_{OUT}=1.0V$		0.01	0.1	%/V
	V_{BIAS} Line Regulation	$3.0V<V_{BIAS}<5.5V$, ($V_{BIAS}>V_{OUT}+1.6$) $V_{OUT}=1.0V$		0.01	0.1	%/V
$PSRR^{(3)}$	Ripple Rejection	V_{IN} to V_{OUT} , $f=1kHz$, $V_{IN}=V_{OUT}+0.5V$, $V_{OUT}=1.0V$, Ripple 0.2Vp-p, $I_{OUT}=30mA$		70		dB
		V_{BIAS} to V_{OUT} , $f=1kHz$, $V_{IN}=V_{OUT}+0.5V$, $V_{OUT}=1.0V$, Ripple 0.2Vp-p, $I_{OUT}=30mA$		70		
$e_N^{(3)}$	Output Noise	$V_{IN}=V_{OUT}+0.5V$, $f=10Hz$ to $100kHz$, $I_{OUT}=1mA$		$60^* V_{OUT}$		μV_{RMS}
I_{EN}	EN Pull-down Current	$V_{EN}=5.5V$, $V_{BIAS}=5.5V$			3	μA
V_{ENH}	EN Input Voltage High		1.0			V
V_{ENL}	EN Input Voltage Low				0.4	V
R_{DIS}	Output resistance of auto discharge at off state	$V_{EN}=0V$, $V_{OUT}=0.5V$		150	250	Ω

ET5A4ADJZB

Electrical Characteristics(Continued)

(Unless otherwise noted, $V_{IN}=V_{OUT}+0.3V$, $V_{BIAS}=3.0V$, $I_{OUT}=10mA$, $C_{IN}=10\mu F$, $C_{OUT}=22\mu F$, $C_{BIAS}=1\mu F$, $T_A=-40\sim+85^{\circ}C$. Typical values are at $T_A=25^{\circ}C$)

$V_{TRLD}^{(3)}$	Load Transient	$I_{OUT}=1mA$ to $1500mA$ in $10\mu s$ $V_{IN}=V_{OUT}+0.2V$, $T_A=25^{\circ}C$		65* V_{OUT}	90* V_{OUT}	mV
		$I_{OUT}=1500mA$ to $1mA$ in $10\mu s$ $V_{IN}=V_{OUT}+0.2V$, $T_A=25^{\circ}C$		65* V_{OUT}	90* V_{OUT}	mV
T_{ON}	Turn-On Time	$V_{OUT}=1.0V$, From assertion of V_{EN} to $V_{OUT}=90\%V_{OUT(NOM)}$		320		μs
T_R	Rise Time	$V_{OUT}=1.0V$, From assertion of $V_{OUT}=10\%$ to $90\%V_{OUT(NOM)}$		200		μs
$T_{TSD}^{(3)}$	Thermal Shutdown Threshold	T_J rising		160		$^{\circ}C$
$T_{HYS}^{(3)}$	Thermal Shutdown Hysteresis	T_J falling from shutdown		20		$^{\circ}C$

Notes:

1: The maximum input voltage should take into account the maximum power consumption ($P_D(max)$). The calculation formula is as follows:

$$P_D(max) = (V_{IN(max)} - V_{OUT}) \times I_{OUT}$$

The maximum power consumption of the circuit is 1500mW.

$$V_{IN(max)} = 1500mW / I_{OUT} + V_{OUT}$$

For example:

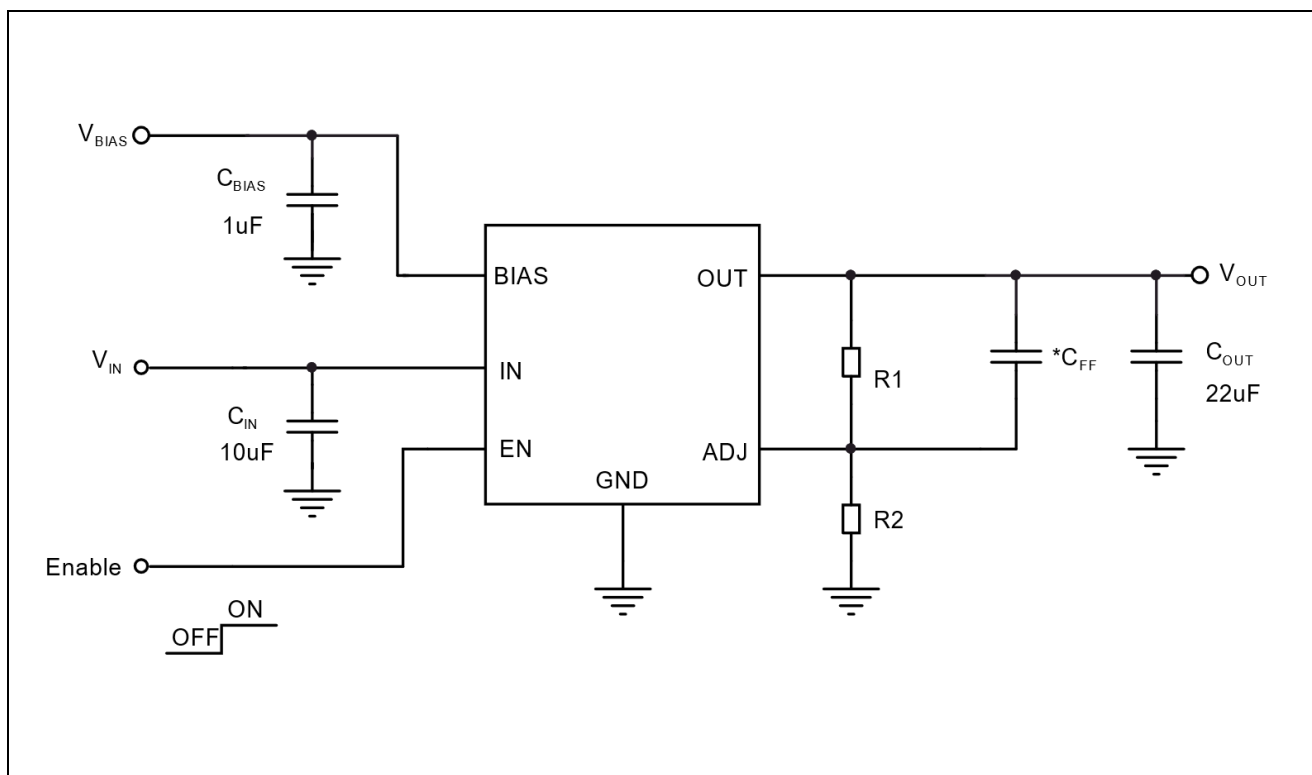
If $V_{OUT}=1.0V$, $I_{OUT}=1000mA$, The maximum input voltage is $V_{IN(max)}=1500mW/1000mA+1.0=2.5V$

2: V_{DROP} FT test method: test the V_{OUT} voltage at $V_{SET}+V_{DROPMAX}$ with output current.

3: Guaranteed by design and characterization, not a FT item.

ET5A4ADJZB

Application Circuits



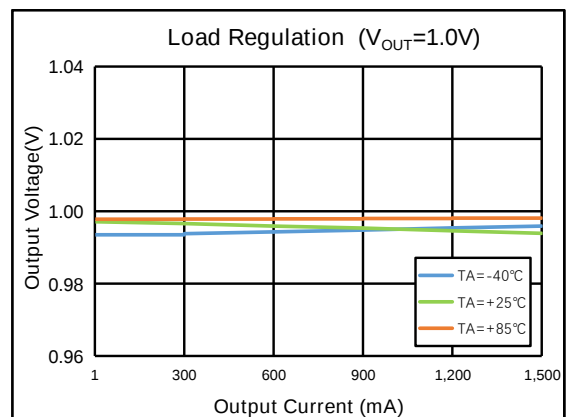
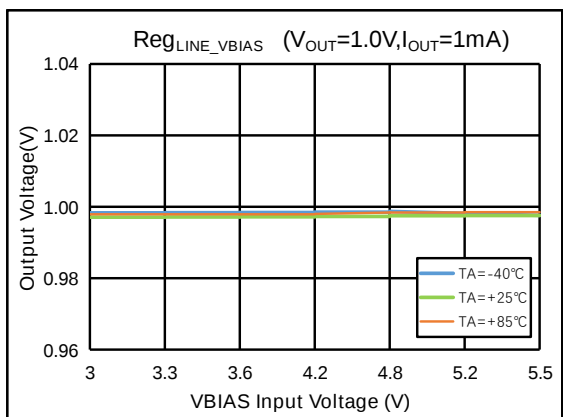
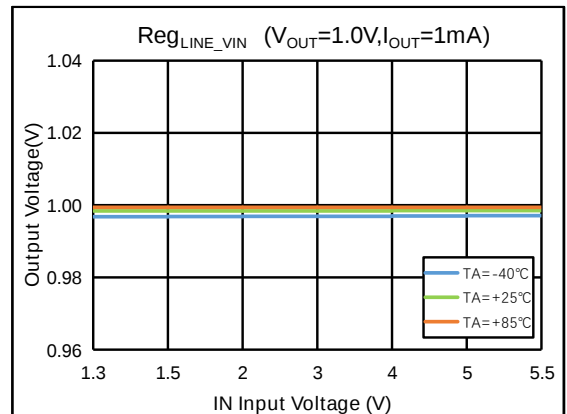
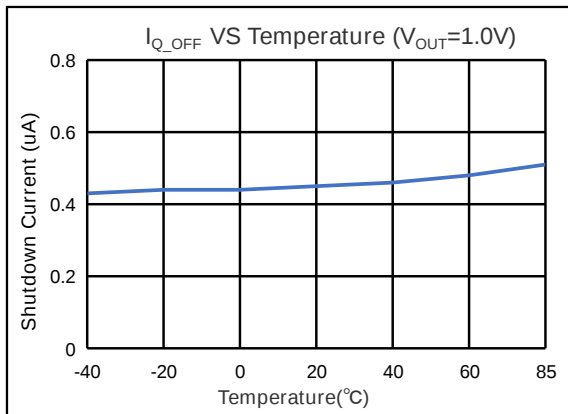
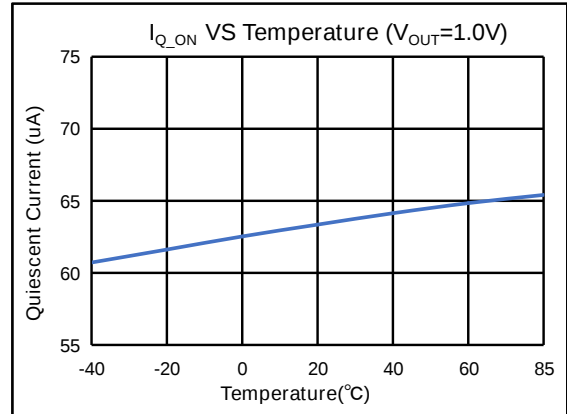
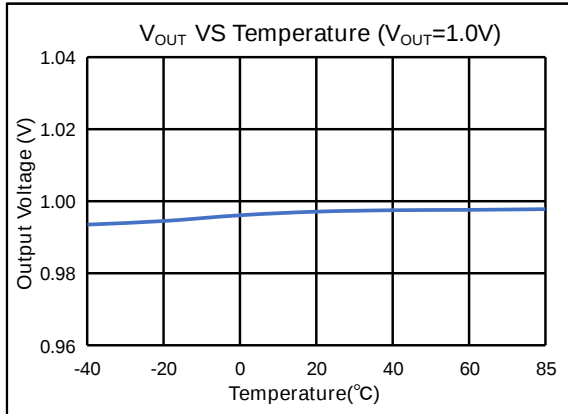
Note*: $V_{OUT} = 0.5 \times (1 + R1/R2)$, $(R1 + R2)$ no greater than 100k Ω . The feedforward capacitor C_{FF} is optional for the optimization of transient response, suggested value is 10nF.

ET5A4ADJZB

Typical Characteristics

Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

($V_{IN}=1.30V$, $V_{BIAS}=3.0V$, $I_{OUT}=1mA$, $C_{IN}=10\mu F$, $C_{OUT}=22\mu F$, $C_{BIAS}=1\mu F$, $V_{OUT}=1V$)

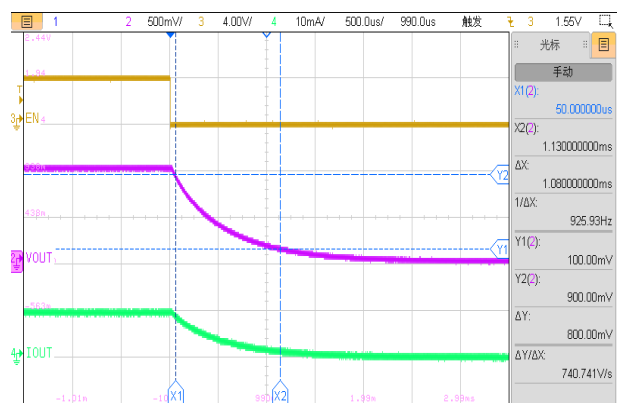
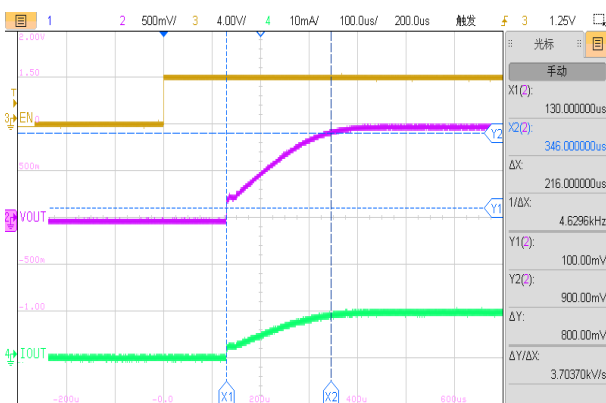
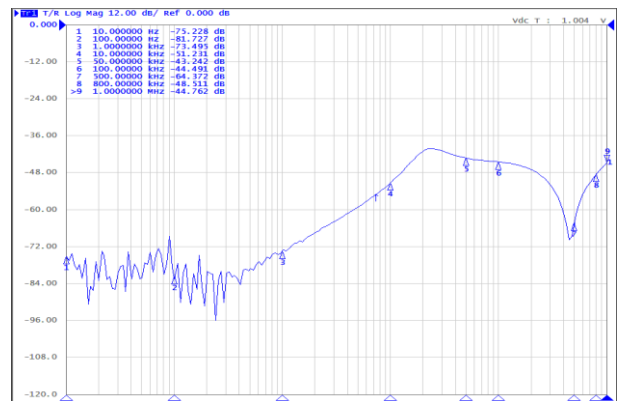
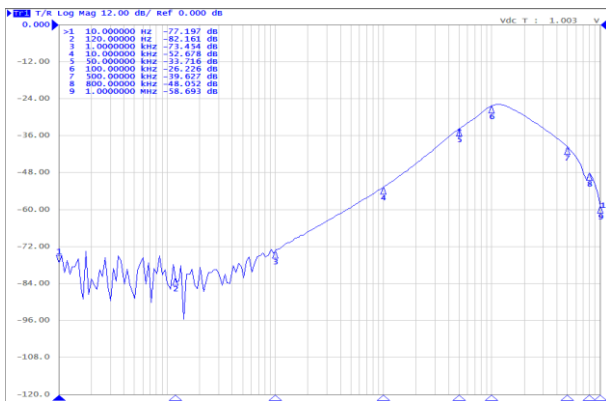
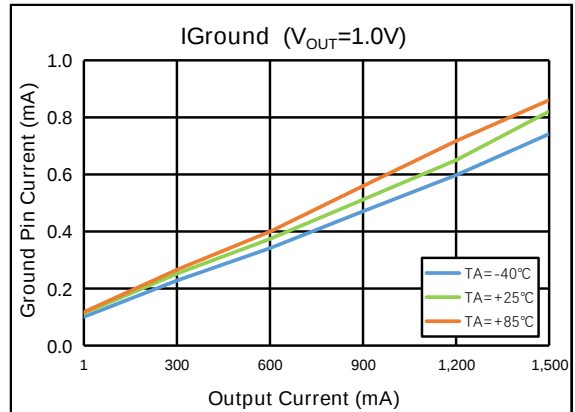
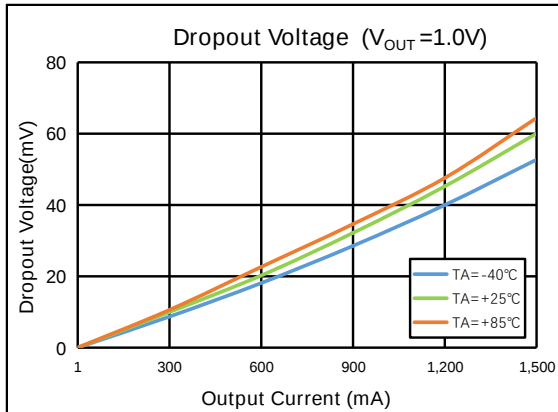


ET5A4ADJZB

Typical Characteristics (Continued)

Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

($V_{IN}=1.30V$, $V_{BIAS}=3.0V$, $I_{OUT}=1mA$, $C_{IN}=10\mu F$, $C_{OUT}=22\mu F$, $C_{BIAS}=1\mu F$, $V_{OUT}=1V$)

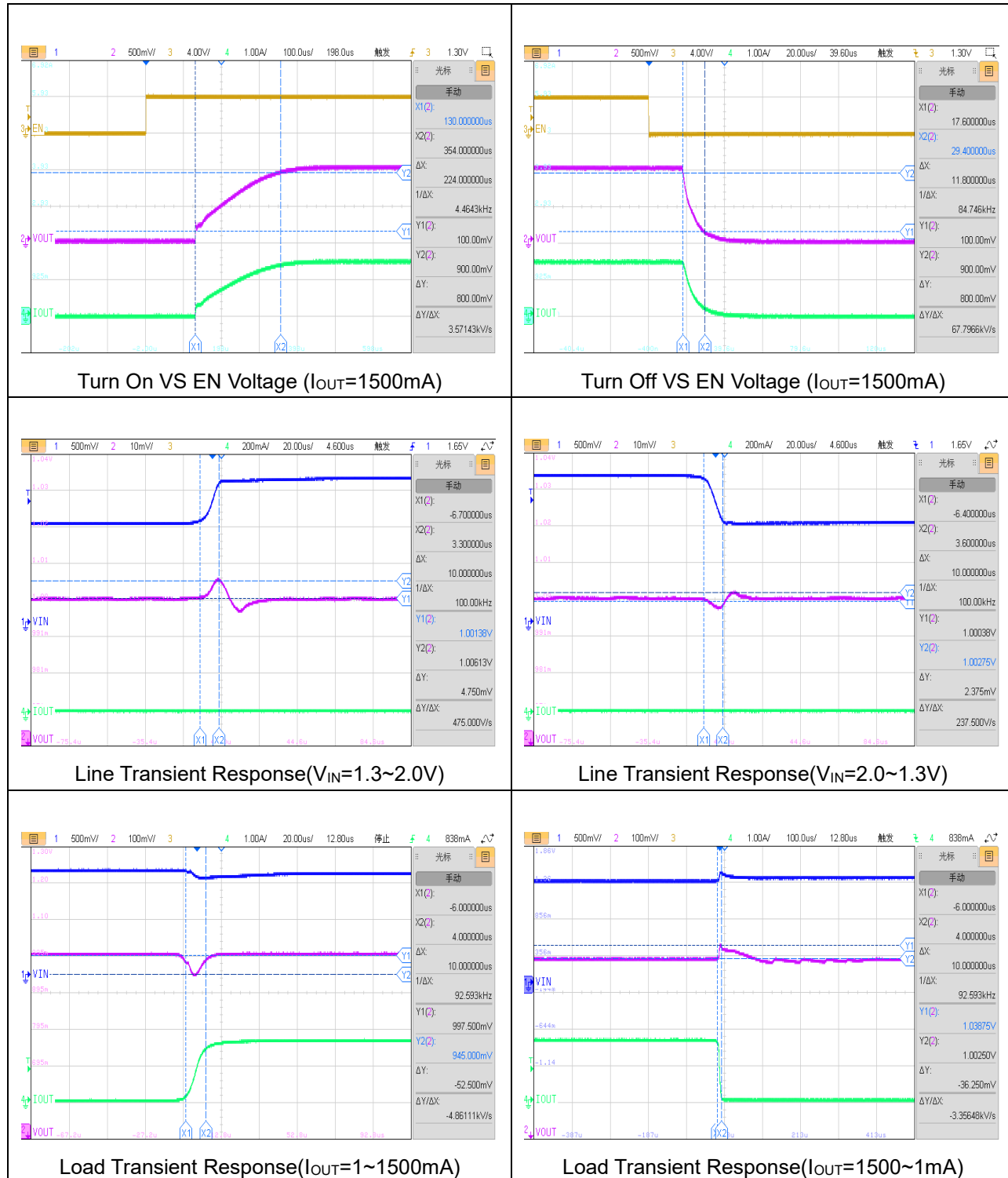


ET5A4ADJZB

Typical Characteristics (Continued)

Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

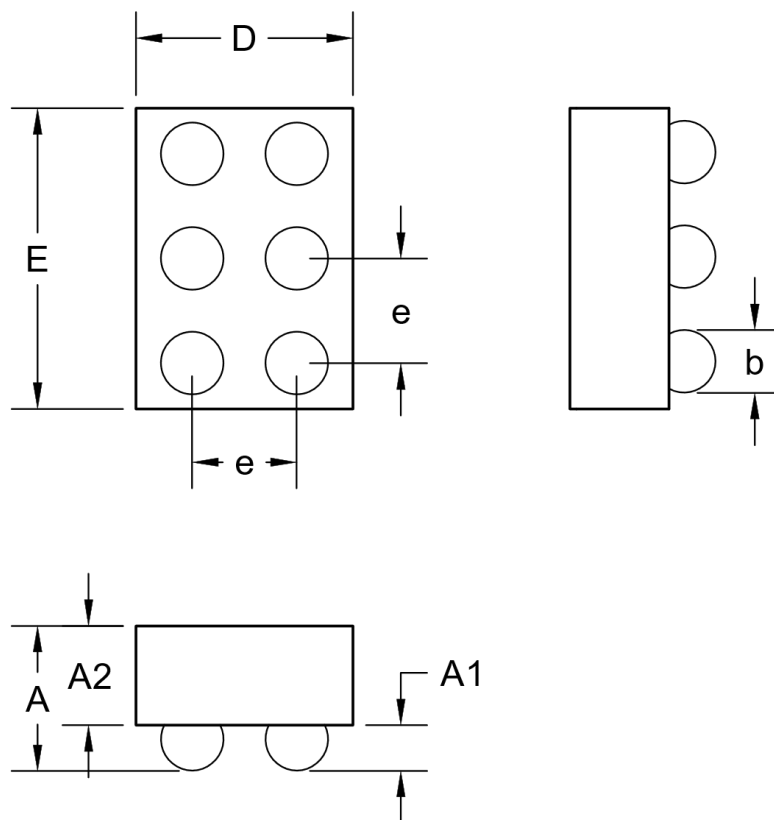
($V_{IN}=1.30V$, $V_{BIAS}=3.0V$, $I_{OUT}=1mA$, $C_{IN}=10\mu F$, $C_{OUT}=22\mu F$, $C_{BIAS}=1\mu F$, $V_{OUT}=1V$)



ET5A4ADJZB

Package Dimension

WLCSP6

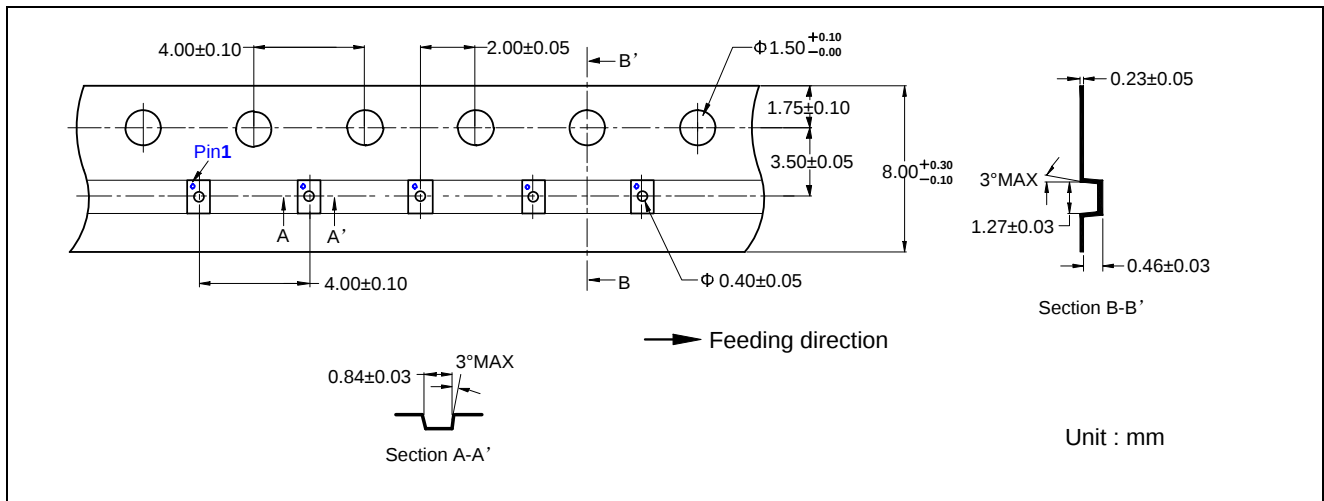


Dimensions Table (Units: mm)

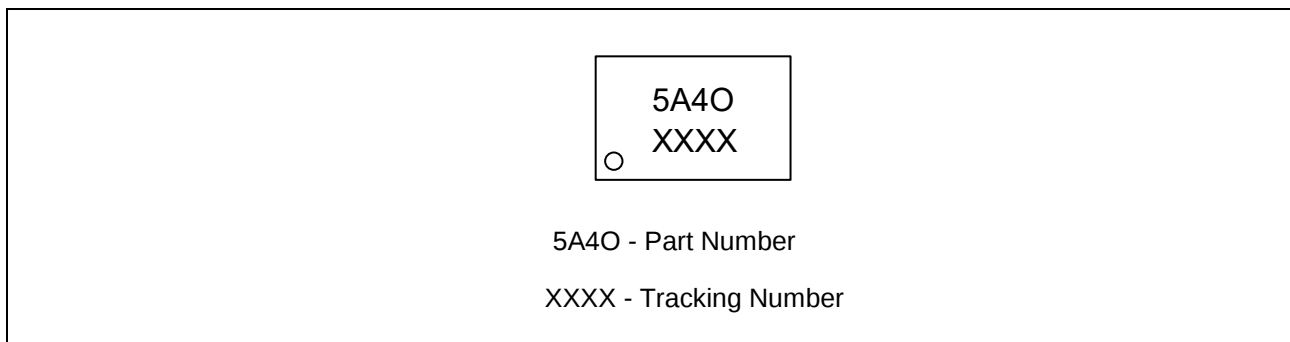
Symbol	Min	Nom	Max
A	0.32	0.36	0.39
A1	0.06	0.08	0.10
A2	0.26	0.28	0.30
b	0.22	0.24	0.26
D	0.754	0.774	0.804
E	1.156	1.176	1.206
e	0.400 BSC		

ET5A4ADJZB

Tape Information



Marking Information



Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
0.0	2022-11-22	Preliminary Version	Tugz	Liuxm	Liujiy
1.0	2023-04-12	Official Version	Tugz	Liuxm	Liujiy
1.1	2024-12-21	Update Electrical Characteristics & Typical Characteristics	Pengjj	Liuxm	Liujiy